Temperature issues with white laser diodes, calculation and approach for new packages

Roland Lachmayer*, Gerolf Kloppenburg, Serge Stephan
Leibniz Universität Hannover, Institute of Product Development, Welfengarten 1A, 30167 Hannover, Germany

ABSTRACT

Bright white light sources are of significant importance for automotive front lighting systems. Today’s upper class systems mainly use HID or LED light sources. As a further step laser diode based systems offer a high luminance, efficiency and allow the realization of new dynamic and adaptive light functions and styling concepts.

The use of white laser diode systems in automotive applications is still limited to laboratories and prototypes even though announcements of laser based front lighting systems have been made. But the environment conditions for vehicles and other industry sectors differ from laboratory conditions. Therefore a model of the system’s thermal behavior is set up.

The power loss of a laser diode is transported as thermal flux from the junction layer to the diode’s case and on to the environment. Therefor its optical power is limited by the maximum junction temperature (for blue diodes typically 125 - 150 °C), the environment temperature and the diode’s packaging with its thermal resistances. In a car’s headlamp the environment temperature can reach up to 80 °C. While the difference between allowed case temperature and environment temperature is getting small or negative the relevant heat flux also becomes small or negative. In early stages of LED development similar challenges had to be solved. Adapting LED packages to the conditions in a vehicle environment lead to today’s efficient and bright headlights. In this paper the need to transfer these results to laser diodes is shown by calculating the diodes lifetimes based on the presented model.

Keywords: Laser, Automotive lighting, Laser activated remote phosphor, Thermal management of laser diodes, Lifetime modeling

1. INTRODUCTION

An increase of luminous efficiency of bright white LEDs over the past years has led to a rapidly growing number of LED systems being used for general lighting applications. Also in automotive front lighting, LEDs are replacing halogen lamps and Xenon discharge lamps. Typically, the white light of the LED is generated by covering a blue chip with a phosphor coating [1]. A part of the emitted blue light is then absorbed by the phosphor and converted to a spectrum band from green to red. The rest of the emitted light stays unconverted and is then mixed with the converted spectrum. The balance between converted and unconverted light as well as the chemical mixture of the phosphor allow the generation of a desired color temperature. Advances in LED systems’ packaging have made very bright white light sources consisting of a single LED chip possible by optimizing the thermal coupling of the elements.

Laser diodes are technologically similar to an LED and the interest to develop high power laser diode systems is constantly rising. One of the reasons for this is the possibility to use a focused high-energy beam for optical setups and thus build smaller and lighter optics. It is also possible to build systems with a remote phosphor which allow an improved thermal management because there are two separated heat sources [2]. This kind of white light sources is already integrated in various models of multimedia projectors. There are three general approaches to generate white light from laser diodes. Two of them are based on the (remote) phosphor technology and one is to add beams of different wavelengths. The principles are shown in Figure 1.
When using LED or laser diodes for lighting applications usually multiple diodes have to be integrated into one system including electrical power supply and output control. Usually these systems consist of many parts that will cause the whole system to stop working when one element is damaged. Because of this, lifetime considerations for each component are a very important part in the development process of semiconductor systems.

### 2. LIFETIME CALCULATIONS

Lifetime calculations for laser diode systems can be done similar to LEDs. The method has been presented already in [3]. When using lifetime information about laser diodes from data sheets, they are usually referring to a case temperature of 25 °C at nominal current. The damage processes of LED and laser diode chips are similar and as a result the nominal lifetimes are comparable. Values given for laser diodes are around 30,000 hours. Increasing operating temperatures lead to a decrease in theoretical lifetime. To calculate the lifetime $L_n$ at a temperature level $T_n$, the following equation based on Arrhenius’ description of the temperature dependence of reaction rates can be used [4]:

$$L_n = L_{ref} \cdot e^{\left(\frac{E_a}{k_B(T_n - T_{ref})}\right)}$$  \hspace{1cm} (1)

With: $E_a$: Activation Energy, $k_B$: Boltzmann Constant, $T_{ref}$: Reference Temperature, $L_{ref}$: Measured Lifetime at Temperature $T_{ref}$, the exponential term is called acceleration factor $b$.

$$L_n = L_{ref} \cdot b$$  \hspace{1cm} (2)

Operating temperatures may vary during the product usage period. This is caused by changing environmental conditions as well as different operating currents. For automotive applications the specified environment temperature range is from −40 °C to +80 °C. The same light sources are often used for various lighting functions such as tail light and breaking light. In this case different operating conditions and thus thermal loads occur. These actual operating conditions have to be taken into account to approximate the diode’s lifetime.

The total real lifetime of a laser diode can be split into $\sum_i \Delta \tau_i$ time intervals with constant temperature loads $T_i$.

$$L_n = \sum_{i=1}^{n} \Delta \tau_i$$  \hspace{1cm} (3)

The damage equivalent time for operation at $T_{ref}$ in $\Delta \tau_i$ can be calculated by

$$\Delta t_i = \Delta \tau_i \cdot b_i^{-1}$$  \hspace{1cm} (4)

If $\sum_i \Delta t_i$ sum exceeds the reference lifetime, then the laser diode is permanently damaged. Equation (5) shows a context of this.

$$L_{ref} \geq \sum_{i=1}^{n} \Delta t_i \cdot b_i^{-1}$$  \hspace{1cm} (5)

For infinitesimal small time elements $\Delta \tau_i$ the sum can be replaced by an integral.
\[
L_{\text{ref}} \geq \int_{0}^{T} e^{-\frac{E_o}{k_B(T\tau - T_{\text{ref}})}} d\tau
\]

(6)

Is the function of \( T(\tau) \) thus the maximum new lifetime can be predicted. Or is it possible to estimate lifetime at any time point to the lifetime end.

3. SYSTEM EFFICIENCY AND LONG TERM BEHAVIOR

The system set up in chapter 4.3 is used to determine the long term behavior of the white laser light source. Regarding an automotive application, the light source has to achieve a minimum lifetime of 1000 hours. For the use of the laser system as a low beam light source, a luminous flux of 1000 lumens has to be generated. The previously built light source has an optical output of 200 lm at 1200 mA input current and a case temperature of 25 °C \(^4\). So theoretically an amount of 5 laser diodes is necessary to achieve the optical output specified. The thermal resistance between junction layer and case is a crucial value for the system’s thermal behavior. For the laser diodes used it is 15 K/W. Due to the chip design and manufacturing processes of the diode, this property can only be optimized by the manufacturer. In comparison today’s automotive LEDs achieve resistances of about 2 K/W (see Table 1).

In Figure 2 a comparison of wall-plug efficiencies for selected LEDs and the white laser diode system is shown. To calculate the wall-plug efficiency, electrical input power \( P_{el} \) of the system and the total luminous flux \( \Phi \) in lumens is used. The datasheets of LEDs give information about the change of input voltage at different temperatures for a controlled input current as well as the corresponding change in the luminous flux. Values for the laser diode system are measured according to the description in section 4.3.

Table 1. Comparison of white diodes for automotive applications (Values from data sheets, except for luminous flux of No. 7) \(^{5,6,7,8,9,10}\)

<table>
<thead>
<tr>
<th>No.</th>
<th>Diode</th>
<th>Max. ( T_j ) (°C)</th>
<th>Max Thermal Resistance Rjc</th>
<th>Luminous Flux</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>OSLON Black Flat KW H2L531.TE</td>
<td>150</td>
<td>1.9 K/W</td>
<td>500…800 lm @ 1000 mA</td>
</tr>
<tr>
<td>2</td>
<td>OSLON Black Flat LUW H9QP</td>
<td>150</td>
<td>7.5 K/W</td>
<td>180…280 lm @ 700 mA</td>
</tr>
<tr>
<td>3</td>
<td>OSRAM OSTAR LE UW U1A3 01</td>
<td>150</td>
<td>3.6 K/W</td>
<td>630…1120 lm @ 1000 mA</td>
</tr>
<tr>
<td>4</td>
<td>OSRAM OSTAR LE UW U1A5 01</td>
<td>150</td>
<td>2.5 K/W</td>
<td>1120…1800 lm @ 1000 mA</td>
</tr>
<tr>
<td>5</td>
<td>PHILIPS LXMA-PW01-0110</td>
<td>150</td>
<td>10 K/W</td>
<td>199 lm @ 700 mA</td>
</tr>
<tr>
<td>6</td>
<td>PHILIPS LXMA-PW01-0130</td>
<td>150</td>
<td>10 K/W</td>
<td>233 lm @ 700 mA</td>
</tr>
<tr>
<td>7</td>
<td>OSRAM PL TB450B (+ phosphor added)</td>
<td>150</td>
<td>15 K/W</td>
<td>205 lm@ 1200 mA, ( T_{\text{case}}=20°C )</td>
</tr>
</tbody>
</table>
Using two LED sources (No. 1 and 4) from Table 1 as an example, the amount of diodes necessary to achieve 1000 lm is calculated and shown in Table 2. Since the necessary input current for a 1000 lm system will be lower than the specified maximum, the diodes’ lifetime will increase.

Table 2. Required amount of diodes and resulting input current for 1000 lm

<table>
<thead>
<tr>
<th>Diode</th>
<th>Required Diodes for 1000 lm at T\text{\textsubscript{case}} = 25 °C</th>
<th>Operating current per Diode (I\text{\textsubscript{F}})</th>
</tr>
</thead>
<tbody>
<tr>
<td>OSLON Black Flat KW H2L531.TE</td>
<td>2</td>
<td>720 mA</td>
</tr>
<tr>
<td>OSRAM OSTAR LE UW U1A5 01</td>
<td>1</td>
<td>630 mA</td>
</tr>
<tr>
<td>OSRAM PL TB450B (+ phosphor added)</td>
<td>5</td>
<td>1200 mA</td>
</tr>
</tbody>
</table>

4. SYSTEM DESIGN AND MODELING

The system evaluated consists of a laser diode with 450 nm peak wavelength and an external power supply. The light output is focused on a remote phosphor layer which partially converts the blue light to light of higher wavelengths (480-650 nm). This optical system can be regarded as a white light source. There is no thermal coupling between laser diodes and remote phosphor layer except for the optical beam. The case temperature of the laser diode is controlled to values between 25 and 50 °C.

4.1 Thermal equivalent circuit diagram

The thermal equivalent circuit diagram in Figure 3 is based on the assumption of a stationary system for the time period \( dt \) without transient processes. The thermal eigentime constant \( \lambda_{LP} \) of the laser diode has to be significantly smaller than \( dt \). The electrical input power \( P_{\text{el}} \) is partly transferred as light energy \( P_{\text{opt}_1} \) to the remote phosphor layer. The resulting optical power after passing the conversion layer is \( P_{\text{opt}_2} \). The differences between \( P_{\text{el}}, P_{\text{opt}_1} \) and \( P_{\text{opt}_2} \) represent the power dissipation at each element. This power dissipation is lead away passing thermal resistances of the system’s components. The thermal equivalent resistance between junction layer and case is \( R_{\text{jlc}} \), between case and environment \( R_{\text{cs}} \) and between conversion layer and environment \( R_{\text{con}_a} \).
4.2 Modelling a laser based white light source with lifetime approximation

The previously gathered system characteristics in combination with the thermal equivalent circuit diagram and Arrhenius’ equation are combined to a Matlab Simulink model (Figure 4).

Input parameters are the diode’s case temperature and the electrical current input. The measured characteristic maps are used as input data for the model blocks TIU and TIPopt1 to calculate P_el, P_opt_1 and the junction temperature T_j. The junction temperature T_j is used according to equation (6) to estimate the diode’s lifetime. The parameters case temperature and input current can be varied during the simulation to model different load cases.

Further elements are implemented to approximate the luminous flux and the wall plug efficiency of the whole system. In order to achieve a constant light output the input current of the system can be controlled. With these additions, the modeled system is very well approximated to the real situation in a vehicle.
4.3 Model parameters and setup

In an experimental setup the system characteristics have been measured. A laser diode is placed opposed to a reflective phosphor layer inside an integrating sphere. The sphere is used to measure the optical power $P_{\text{opt,2}}$ for different case temperatures $T_{\text{case}}$ and operating currents $I_{\text{LD}}$. To measure $P_{\text{opt,1}}$ a thermal power sensor head is used. A laser diode controller is used to generate and measure the electrical power $P_{\text{el}}$. The data is combined to a characteristic map of the diode’s output power. Using a thermal imaging system the temperature of the phosphor layer is measured. Due to the phosphor layer being coated on a relatively large aluminum plate the temperature rise caused by the laser beam is quite low ($\leq 8$ K). Therefore its temperature as well as the conversion efficiency are considered to be constant for the thermal model and calculations.

The calculations of laser diode systems in the model are based on existing reliability assumptions of LEDs. Typically their lifetime is between 20,000 and 50,000 hours at a junction temperature of $T_j = 25$ °C. The technical information provided by the LED’s manufacturer indicate a value of 100 hours at $T_j = 175$ °C. The activation energy can be calculated according to equation (1). Based on 50,000 hours lifetime at $T_j = 25$ °C, this leads to $E_A = 0.477$ eV. The activation energy of the laser diode modelled is considered to be of similar size.

4.4 Simulation and analysis

Using this approach the lifetime of the laser diodes can be calculated depending on the thermal resistance $R_{\text{jc}}$ and the case temperature $T_{\text{case}}$ (Figure 6). The required minimum lifetime of 1000 hours corresponds with a junction temperature of 100 °C.

![Figure 6](http://proceedings.spiedigitallibrary.org/ss/termsofuse.aspx)

Figure 6. a) Simulation results for Lifetime during $R_{\text{jc}}$ at 25.35 and 45 °C and target lifetime. b) Calculated junction temperature during $R_{\text{jc}}$. 

---

Figure 5. Light flux regulated model of laser based white light source
As a result of higher temperatures the luminous flux is also reduced (Figure 2). At a case temperature of 50 °C for example, the luminous flux of the laser diode system is 146 lumens. To achieve higher luminous flux at this temperature, the input current of the diode has to be increased. As the diode is already driven at the maximum input current of 1200 mA, this is not possible. For this reason the required amount of diodes in Table 2 has to be even higher. To be able to control the luminous flux of the diode system, the nominal laser current has to be lower than the maximum value. Considering this, 7 laser diodes each generating 146 lm are necessary to achieve the desired luminous flux of 1000 lm.

Using the system model explained in section 4.2 the long term behavior of the system is analyzed for cyclic loads. This is done by activating the regulation of the output flux in the model and setting the target flux value to 146 lm. The temperature of the laser diode is now varied between 25 °C and 50 °C using a sine function. This is done to simulate phases of warming up and cooling down during operation. As a result of this simulation, a lifetime of 949.5 hours can be estimated.

The diode system simulated in Figure 7 has a simulated lifetime close to the specified 1000 hours. To apply this approach to a real system e.g. a car’s headlamp, additional influence factors have to be taken into consideration. Environment temperatures in this case are specified up to 80 °C. Without changes in the system’s setup these temperatures lead to a lifetime reduction by factor 18 compared to an operation at 25 °C (at Rjc = 18 K/W). So in this case an active cooling system is necessary to keep the system’s lifetime. This leads to an increased power consumption and thus lowers the system’s efficiency. Otherwise it would be necessary to reduce the thermal resistance between junction layer and case Rjc to a maximum of 4 K/W.

Figure 7. Simulation results for cycle T_case thermal Load and activated output flux Phi regulation to 146 lm. I_LD is the diode current during load cycles. Lifetime line shows the lifetime history/progress during the load.
5. CONCLUSIONS AND OUTLOOK

In an experimental setup thermal effects on laser diode based white light sources have been evaluated. Based on these experimental data and information from LED data sheets, a lifetime simulation model was set up. This model is a first step to modelling and analyzing current state of the art of laser based white light sources. The simulation is able predict the diode’s lifetime and the system’s light output for specific applications and at any thermal load case.

In order to optimize the prediction of lifetime behavior, exact data for the reliability of laser diodes are necessary. Furthermore the reliability of the whole system has to be considered, i.e. power supply, cooling system and the diodes. The presented model proves that for automotive applications it is necessary to reduce the thermal resistance of laser diodes significantly in order to achieve long lifetimes. Resulting from lower thermal resistances inside laser diodes, the diode’s efficiency and so the wall plug efficiency of the system can be significantly increased. Today’s high power LEDs with thermal resistances of about 2 K/W reach efficiencies of 90 lm/W. Apart from applications needing the high power density of a laser beam, the integration of diode based laser systems can only be useful if their efficiency reaches similar values.

REFERENCES